

INFORMATION DISCLOSURE CITATION
IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)

HALO-02-003

Application Number

10/685,873

Applicant

Seiki Ogura et al.

Filing Date

10/15/03

Group Art Unit

U. S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
T.D	6255166	7/3/01	Ogura et al.	438	257	12/28/99
	6469935	10/22/02	Hayashi	365	185.18	3/19/01
	6531350	3/11/03	Sato et al.	438	197	11/21/01
	6498377	12/24/02	Lin et al.	257	411	3/21/02
	6356482	3/12/02	Derhacopian et al.	365	185.29	9/7/00
	6040995	3/21/00	Reisinger et al.	365	185.18	7/29/97
T.D	5408115	4/18/95	Chang	257	324	4/4/94

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Portion of Pages, Etc.)

T.D	S. Minami et al., "A Novel MONOS Nonvolatile Memory Device Ensuring 10-Year Data Retention after 10 ⁷ Erase/Write Cycles," <u>IEEE Trans. on Electron Device</u> , Vol. 40, No. 11, Nov. 1993, pp. 2011-2017.
T.D	E. Suzuki et al., "Hole and Electron Current Transport in Metal-Oxide-Nitride-Oxide Silicon Memory Structures," <u>IEEE Trans. on Electron Device</u> , Vol. 36, No. 6, June 1989, pp. 1145-1149.

EXAMINER

T. DANG

DATE CONSIDERED

11/10/04

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

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ITALO-02-003

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10/15/03

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[illegible][illegible]

T.D -	T.Y. Cham et al., "A True Single-Transistor Oxide-Nitride-Oxide EEPROM Device", IEEE Electron Device Letters, Vol. EDL-8, No.3, March. 1987.
T.D -	Kuo-Tung Chang et al., "A New SONOS Memory Using Source-Side Injection for Programming", IEEE Electron Device Letters, Vol. 19, No.7, July, 1998.

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11/10/64

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JAN 29 2004

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FOREIGN PATENT DOCUMENTS

OTHER DOCUMENTS (Including Author, Title, Date, Portion, Pages, Etc.)

T.D

Paulo Cappelletti et al., "Flash Memories," Kluwer Academic Publishers 1999, pp. 217-223.

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11/10/04

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